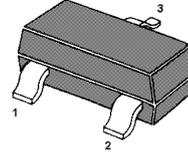


## PNP Silicon Epitaxial Planar Transistor

for high voltage amplifier applications



1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	160	V
Collector Emitter Voltage	$-V_{CEO}$	150	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current Continuous	$-I_C$	600	mA
Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_s$	- 55 to + 150	$^\circ\text{C}$

### Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE} = 5\text{ V}$ , $-I_C = 1\text{ mA}$ at $-V_{CE} = 5\text{ V}$ , $-I_C = 10\text{ mA}$ at $-V_{CE} = 5\text{ V}$ , $-I_C = 50\text{ mA}$	$h_{FE}$ $h_{FE}$ $h_{FE}$	50 60 50	- 240 -	- - -
Collector Cutoff Current at $-V_{CB} = 120\text{ V}$	$-I_{CBO}$	-	50	nA
Emitter Cutoff Current at $-V_{EB} = 3\text{ V}$	$-I_{EBO}$	-	50	nA
Collector Base Breakdown Voltage at $-I_C = 100\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	160	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	150	-	V
Emitter Base Breakdown Voltage at $-I_E = 10\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	5	-	V
Collector Emitter Saturation Voltage at $-I_C = 10\text{ mA}$ , $-I_B = 1\text{ mA}$ at $-I_C = 50\text{ mA}$ , $-I_B = 5\text{ mA}$	$-V_{CE(sat)}$ $-V_{CE(sat)}$	- -	0.2 0.5	V V
Base Emitter Saturation Voltage at $-I_C = 10\text{ mA}$ , $-I_B = 1\text{ mA}$ at $-I_C = 50\text{ mA}$ , $-I_B = 5\text{ mA}$	$-V_{BE(sat)}$ $-V_{BE(sat)}$	- -	1 1	V V
Gain Bandwidth Product at $-V_{CE} = 10\text{ V}$ , $-I_C = 10\text{ mA}$ , $f = 100\text{ MHz}$	$f_T$	100	300	MHz
Output Capacitance at $-V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{obo}$	-	6	pF

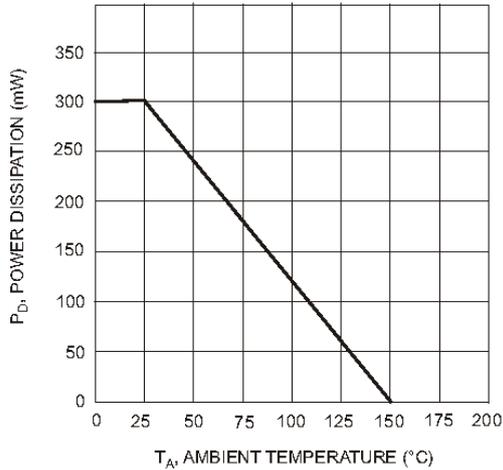


Fig. 1, Max Power Dissipation vs Ambient Temperature

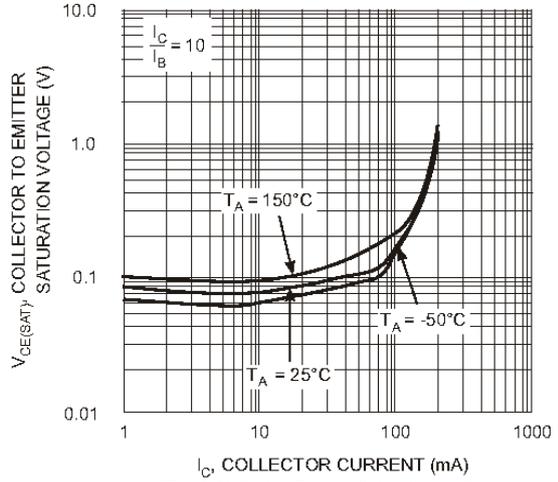


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

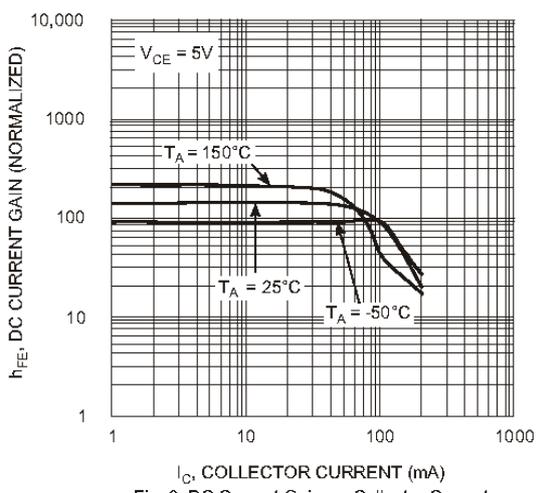


Fig. 3, DC Current Gain vs. Collector Current

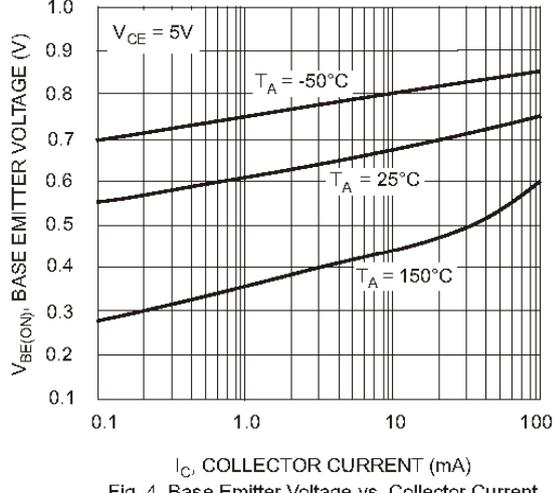


Fig. 4, Base Emitter Voltage vs. Collector Current

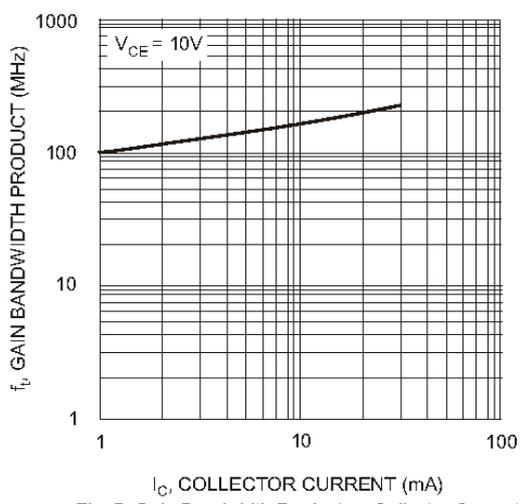


Fig. 5, Gain Bandwidth Product vs Collector Current